



Cite this: *RSC Adv.*, 2018, 8, 31984

DOI: 10.1039/c8ra90075b

[www.rsc.org/advances](http://www.rsc.org/advances)

## Correction: Role of annealing temperature on the sol–gel synthesis of VO<sub>2</sub> nanowires with *in situ* characterization of their metal–insulator transition

Y.-R. Jo, S.-H. Myeong and B.-J. Kim\*

Correction for 'Role of annealing temperature on the sol–gel synthesis of VO<sub>2</sub> nanowires with *in situ* characterization of their metal–insulator transition' by Y.-R. Jo *et al.*, *RSC Adv.*, 2018, 8, 5158–5165.

The authors regret that one of the funders was omitted from the acknowledgements in the original article. The full acknowledgements should read: "This work was supported by the Samsung Research Funding Center of Samsung Electronics under Project Number SRFC-MA1402-10 and the National Research Foundation of Korea (NRF) under Grant NRF2013S1A2A2035468."

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

